NSN 5962-01-053-0019

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-053-0019

Body Length:
Between 0.915 inches and 0.925 inches
Body Width:
Between 0.245 inches and 0.252 inches
Body Height:
Between 0.115 inches and 0.125 inches
Maximum Power Dissipation Rating:
532.48 milliwatts
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and 3-state output and monolithic and w/disable
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Current Rating Per Characteristic:
140.00 milliamperes supply
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Capitance Rating Per Characteristic:
5.00 input picofarads and 8.00 output picofarads
Time Rating Per Chacteristic:
60.00 nanoseconds access
Memory Device Type:
Rom
Terminal Type And Quantity:
18 printed circuit
Shelf Life:
N/a
Unit Of Measure:
_
Demilitarization:

Yes - demil/mli

NSN 5962-01-053-0019

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0